



## **SPECIFICATION**

• Supplier : Samsung electro-mechanics • Samsung P/N : CL10C150FB8NNWC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 15pF, 50V, ±1%, C0G, 0603

## A. Samsung Part Number

<u>CL</u> <u>10</u> <u>C</u> <u>150</u> <u>F</u> <u>B</u> <u>8</u> <u>N</u> <u>N</u> <u>W</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor		
2	Size	0603 (inch code)	L: 1.6 ± 0.1 mm	W: 0.8 ± 0.1 mm
3	Dielectric	C0G	Inner electrode	Ni
4	Capacitance	<b>15</b> pF	Termination	Cu
(5)	Capacitance	±1 %	Plating	Sn 100% (Pb Free)
	tolerance		Product	Normal
6	Rated Voltage	50 V	<b>10</b> Special	Product for Network application
7	Thickness	0.8 ± 0.1 mm	① Packaging	Cardboard Type,7"reel(4,000ea)

## **B. Samsung Reliability Test and Judgement condition**

	Performance	Test condition	
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms	
Q	700 min		
Insulation	More than 500Mohm⋅ <i>μ</i> Γ	Rated Voltage 60~120 sec.	
Resistance			
Appearance	No abnormal exterior appearance	Visual inspection	
Withstanding	No dielectric breakdown or	300% of the rated voltage	
Voltage	mechanical breakdown		
Temperature	COG		
Characteristics	(From -55 ℃ to 125 ℃, Capacitance change should be within ±30PPM/℃)		
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.	
of Termination	terminal electrode		
Bending Strength	Capacitance change: within ±5%	Bending to the limit (1mm)	
		with 1.0mm/sec.	
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder	
	is to be soldered newly	245±5℃, 3±0.3sec.	
		(preheating : 80~120 ℃ for 10~30sec.)	
Resistance to Capacitance change : within ±2.5%		Solder pot : 270±5℃, 10±1sec.	
Soldering heat	Tan δ, IR : initial spec.		

	Performance	Test condition
Vibration Test Capacitance change: within ±2.5%		Amplitude: 1.5mm
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)
		2hours × 3 direction (x, y, z)
Moisture	Capacitance change: within ±7.5%	With rated voltage
Resistance	Q: 150 min	40±2℃, 90~95%RH, 500 +12/-0 hours
	IR : More than 25MΩ·μF	
High Temperature	Capacitance change : within ±3%	With 200% of the rated voltage
Resistance	Q: 312.5 min	Max. operating temperature
	IR : More than $50 \text{M}\Omega \cdot \mu\text{F}$	1000+48/-0 hours
Temperature	Capacitance change : within ±2.5%	1 cycle condition
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25 °C
		→ Max. operating temperature → 25°C
		5 cycles test

## C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260+0/-5°C, 10sec. Max )

<sup>\*</sup> For the more detail Specification, Please refer to the Samsung MLCC catalogue.